

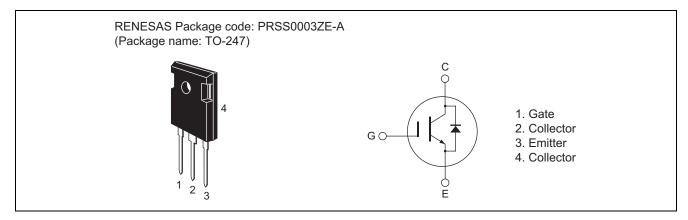
# RJH60M6DPQ-E0

600V - 40A - IGBT Application: Inverter R07DS1088EJ0100 Rev.1.00 Jun 27, 2013

#### **Features**

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)}=1.8~V$  typ. (at  $I_C=40~A,~V_{GE}=15~V,~Ta=25^{\circ}C$ )
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f$  = 50 ns typ. (at  $V_{CC}$  = 300 V,  $V_{GE}$  = 15 V,  $I_C$  = 40 A, Rg = 5  $\Omega$ , Ta = 25°C, inductive load)

### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

	Item	Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	600	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	Tc = 25°C	I <sub>C</sub>	80	А
	Tc = 100°C	I <sub>C</sub>	40	А
Collector peak current		I <sub>C</sub> (peak) Note1	120	A
Collector to emitter diode forward current		I <sub>DF</sub>	50	A
Collector to emitter diode forward peak current		I <sub>DF</sub> (peak) Note1	200	A
Collector dissipation		P <sub>C</sub> Note2	298	W
Junction to case thermal resistance (IGBT)		θj-c <sup>Note2</sup>	0.42	°C/W
Junction to case thermal resistance (Diode)		θj-cd <sup>Note2</sup>	1.07	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

## **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current	I <sub>CES</sub> / I <sub>R</sub>	_	_	5	μA	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0	
/ Diode reverse current	020 11				'	, 52	
Gate to emitter leak current	I <sub>GES</sub>	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.8	2.3	V	$I_C = 40 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V <sub>CE(sat)</sub>		2.2	_	V	$I_C = 80 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies		2500	_	pF	V <sub>CE</sub> = 25 V	
Output capacitance	Coes	_	175	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres	_	100	_	pF	f = 1 MHz	
Total gate charge	Qg	_	170	_	nC	V <sub>GE</sub> = 15 V	
Gate to emitter charge	Qge	_	20	_	nC	V <sub>CE</sub> = 300 V	
Gate to collector charge	Qgc	_	90	_	nC	$I_{C} = 40 \text{ A}$	
Turn-on delay time	t <sub>d(on)</sub>	_	55	_	ns	V <sub>CC</sub> = 300 V	
Rise time	t <sub>r</sub>	_	50	_	ns	V <sub>GE</sub> = 15 V	
Turn-off delay time	t <sub>d(off)</sub>	_	215	_	ns	$I_{C} = 40 \text{ A}$	
Fall time	t <sub>f</sub>	_	50	_	ns	$Rg = 5 \Omega$	
Turn-on energy	E <sub>on</sub>	_	1.11	_	mJ	Inductive load	
Turn-off energy	E <sub>off</sub>	_	0.99	_	mJ	=	
Total switching energy	E <sub>total</sub>	_	2.10	_	mJ	=	
Short circuit withstand time	t <sub>sc</sub>	6	8	_	μs	Tc = 100 °C	
						$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$	
FRD Forward voltage	$V_{F}$	_	1.3	1.8	V	$I_F = 40 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	t <sub>rr</sub>	_	100	—	ns	$I_{F} = 40 \text{ A}$	

FRD reverse recovery charge Q<sub>rr</sub> — 0.22 — FRD peak reverse recovery current I<sub>rr</sub> — 5.0 —

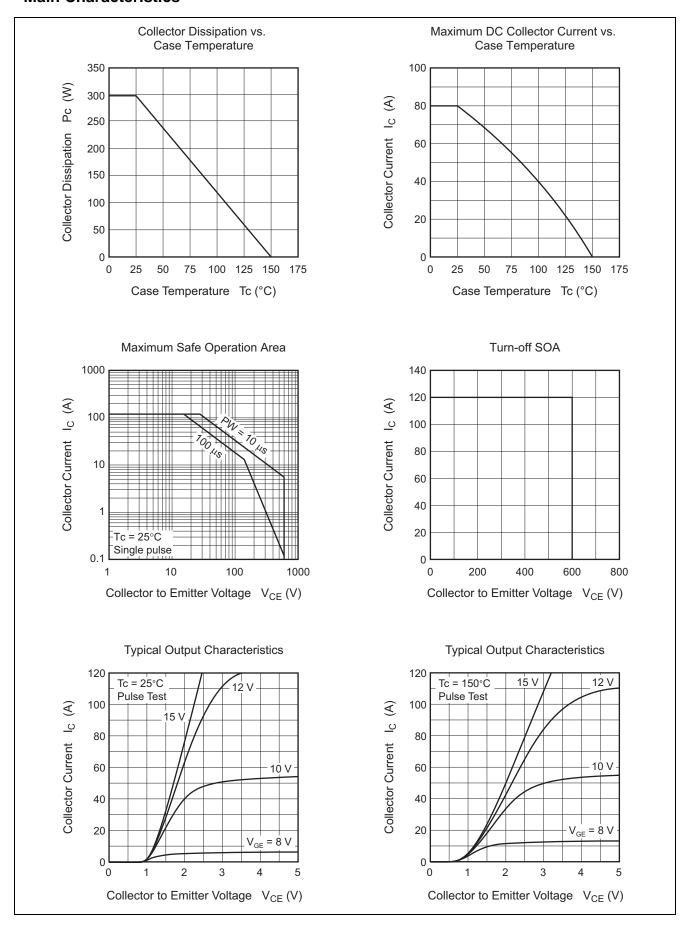
 $I_F = 40 \text{ A}$   $I_F = 40 \text{ A}$   $di_F/dt = 100 \text{ A}/\mu\text{s}$ 

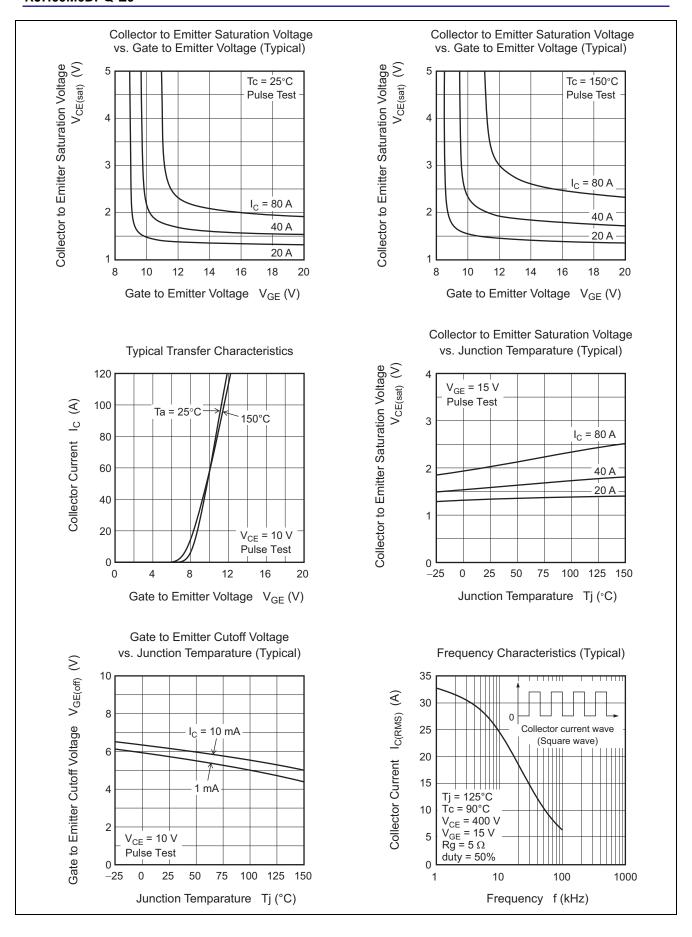
μС

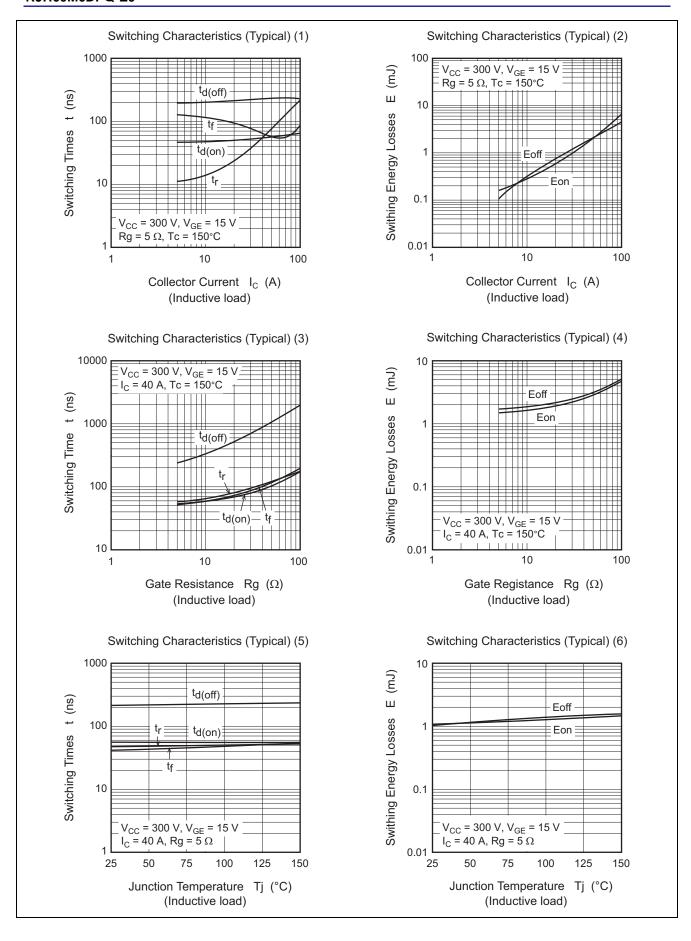
Α

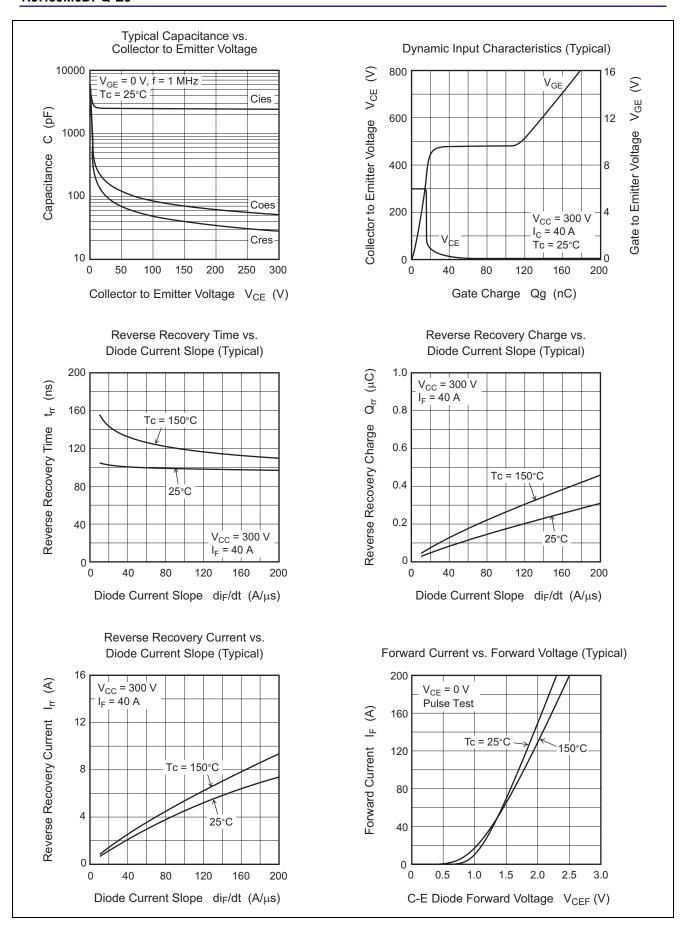
Notes: 3. Pulse test.

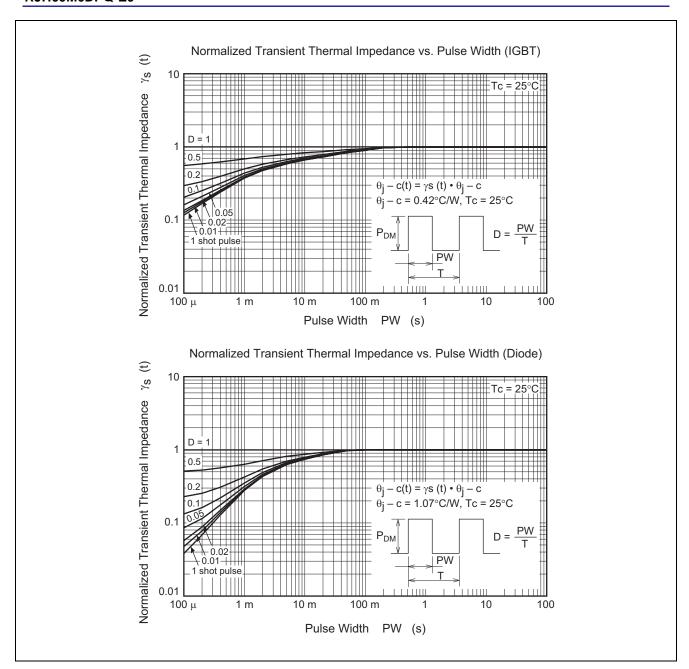
### **Main Characteristics**

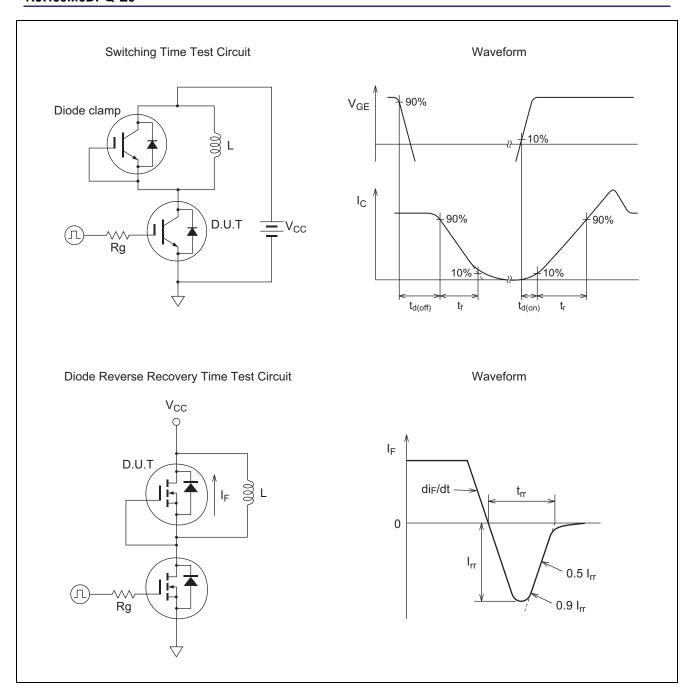




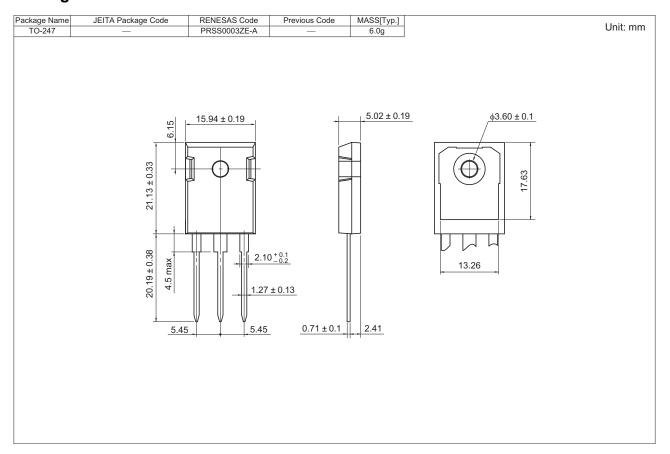








## **Package Dimension**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container	
RJH60M6DPQ-E0#T2	450 pcs	Tube	

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